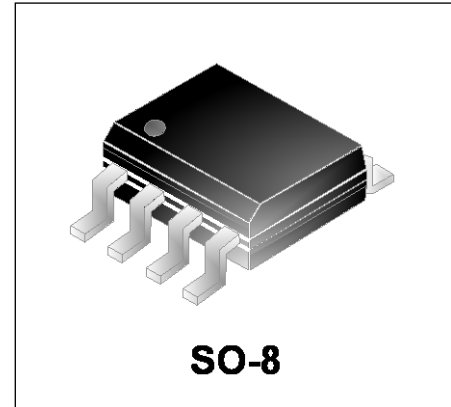


WS05MDAC thru WS24MDAC

Transient Voltage Suppressor

Features

- Bidirectional protection
- Small SO-8 package
- Protects four I/O lines
- Working voltages: 5V, 12V, 15V and 24V
- Low leakage current
- Low operating and clamping voltages
- Solid-state silicon avalanche technology



IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 12A (8/20 μs)

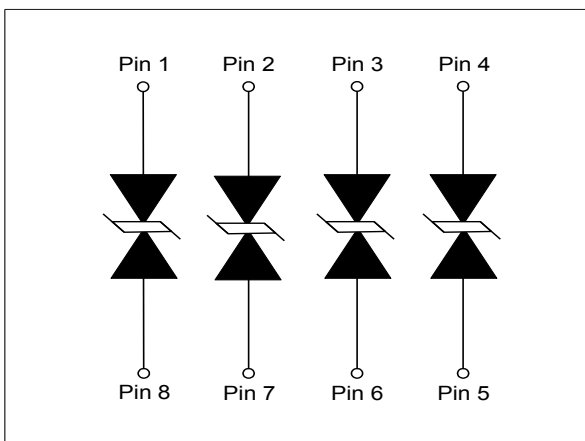
Mechanical Characteristics

- JEDEC SO-8 package
- Molding compound flammability rating: UL 94V-0
- Marking: Part number, date code, logo
- Packaging: Tube or Tape and Reel per EIA 481

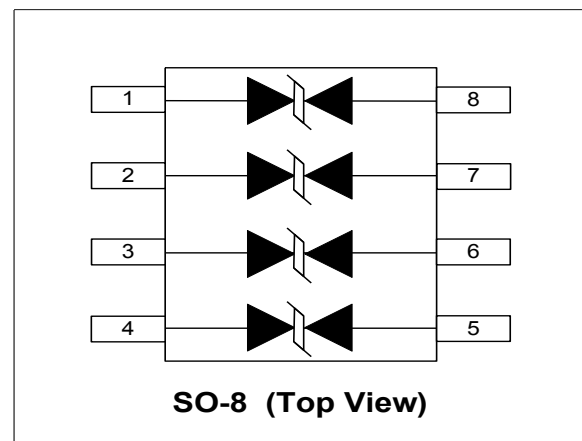
Applications

- data and I/O Lines
- Microprocessor based equipment
- LAN/WAN equipment
- Notebook and Desktops and Servers
- Instrumentation
- Peripherals
- Serial and Parallel Ports

Circuit Diagram (Each Line Pair)



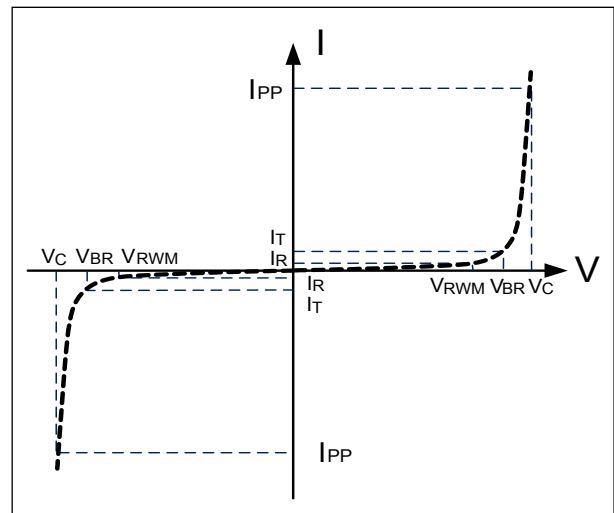
Schematic & PIN Configuration



Absolute Maximum Rating			
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PK}	300	Watts
ESD Voltage (HBM per IEC 61000-4-2)	V_{ESD}	>25	kV
Lead Soldering Temperature	T_L	260 (10 sec.)	°C
Operating Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics

WS05MDAC						
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	6.0			V
Reverse Leakage Current	I_R	$V_{RWM} = 5V, T = 25^\circ C$			20	μA
Clamping Voltage	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$			9.8	V
Clamping Voltage	V_C	$I_{PP} = 5A, t_p = 8/20\mu s$			11	V
Maximum Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			17	A
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$			350	pF

Electrical Characteristics (continued)

WS12MDAC						
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				12	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM}=5V, T=25^{\circ}C$			1	μA
Clamping Voltage	V_C	$I_{PP}=1A, t_p=8/20\mu s$			19	V
Clamping Voltage	V_C	$I_{PP}=5A, t_p=8/20\mu s$			24	V
Maximum PeakPulse Current	I_{PP}	$t_p=8/20\mu s$			12	A
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$			120	pF

WS15MDAC						
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				15	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	16.7			V
Reverse Leakage Current	I_R	$V_{RWM}=5V, T=25^{\circ}C$			1	μA
Clamping Voltage	V_C	$I_{PP}=1A, t_p=8/20\mu s$			24	V
Clamping Voltage	V_C	$I_{PP}=5A, t_p=8/20\mu s$			30	V
Maximum PeakPulse Current	I_{PP}	$t_p=8/20\mu s$			10	A
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$			75	pF

WS24MDAC						
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				24	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	26.7			V
Reverse Leakage Current	I_R	$V_{RWM}=5V, T=25^{\circ}C$			1	μA
Clamping Voltage	V_C	$I_{PP}=1A, t_p=8/20\mu s$			43	V
Clamping Voltage	V_C	$I_{PP}=5A, t_p=8/20\mu s$			55	V
Maximum PeakPulse Current	I_{PP}	$t_p=8/20\mu s$			5	A
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$			50	pF

Typical Characteristics

Figure 1: Non Repetitive Peak Pulse Power vs. Pulse Time

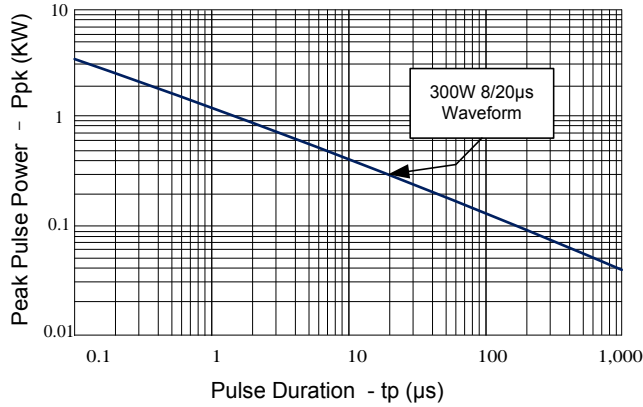


Figure 2: Power Derating Curve

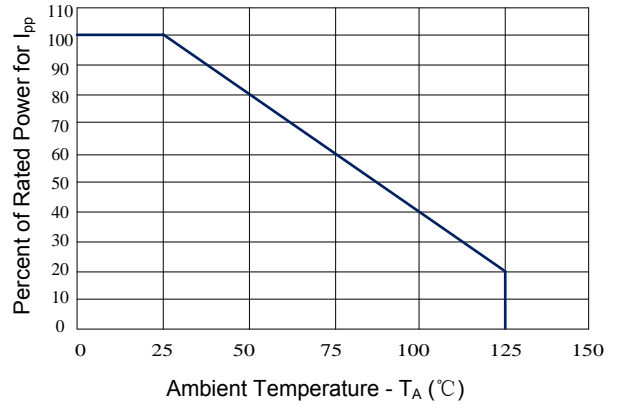


Figure 3: Pulse Waveform

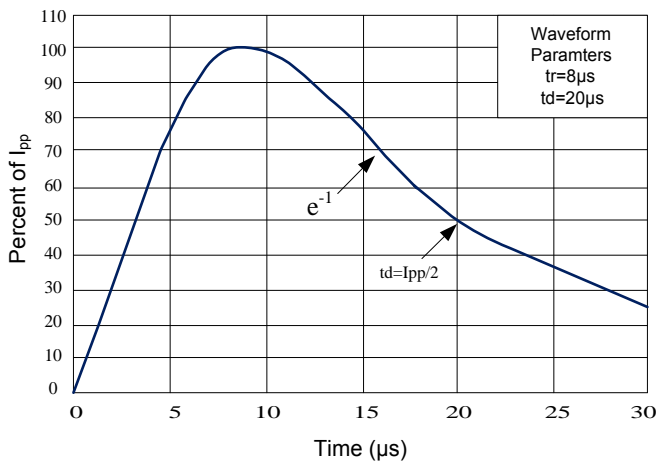


Figure 4: ESD Pulse Waveform (IEC 61000-4-2)

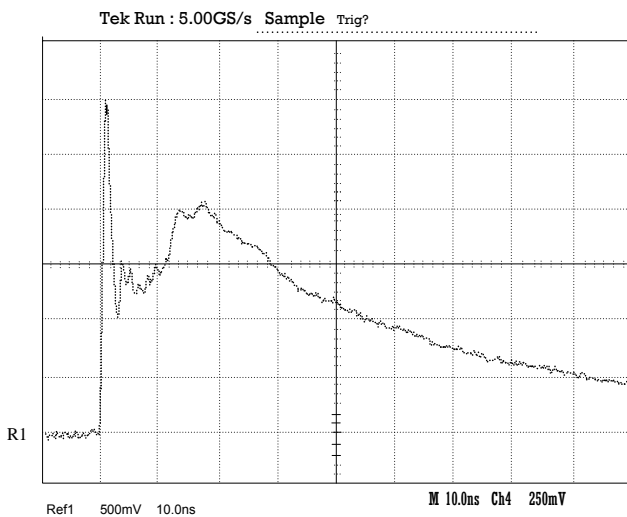


Figure 5: ESD Discharge Parameters Per IEC 61000-4-2

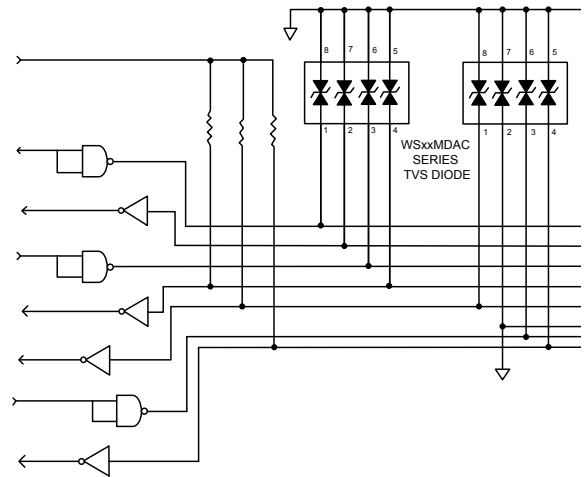
Level	First Peak Current (A)	Peak Current at 30ns (A)	Peak Current at 60ns (A)	Test Voltage (Contact Discharge) (kV)	Test Voltage (Air Discharge) (kV)
1	7.5	4	8	2	2
2	15	8	4	4	4
3	22.5	12	6	6	8
4	30	16	8	8	15

Applications Information

Device Connection for Protection of Four Data Lines

The WSxxMDAC series of devices are designed to protect up to four data lines. The devices are connected as follows:

The WSxxMDAC are unidirectional devices and are designed for use on lines where the normal operating voltage is above ground. Pins 1, 2, 3, and 4 are connected to the protected lines. Pins 5, 6, 7, and 8 are connected to ground. The ground connections should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.



I/O Line protection

Circuit Board Layout Recommendations for Suppression of ESD

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling. Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

Matte Tin Lead Finish

Matte tin has become the industry standard lead-free replacement for SnPb lead finishes. A matte tin finish is composed of 100% tin solder with large grains. Since the solder volume on the leads is small compared to the solder paste volume that is placed on the land pattern of the

PCB, the reflow profile will be determined by the requirements of the solder paste. Therefore, these devices are compatible with both lead-free and SnPb assembly techniques. In addition, unlike other lead-free compositions, matte tin does not have any added alloys that can cause degradation of the solder joint.

